



### HIGH DENSITY MOUNTING AC INPUT, PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



#### DESCRIPTION

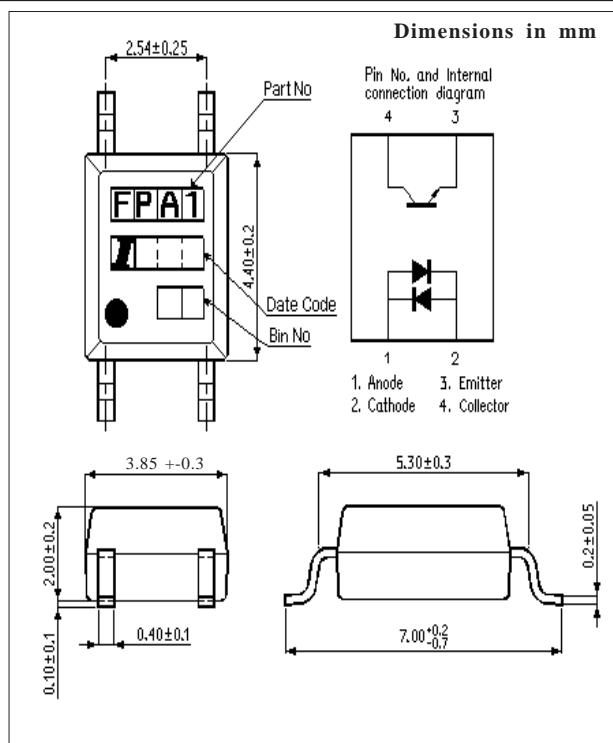
The IS126 is an optically coupled isolator consisting of two infrared light emitting diodes connected in inverse parallel and NPN silicon photo transistor in a space efficient dual in line plastic package.

#### FEATURES

- Marked as FPA1.
- Current Transfer Ratio MIN. 20%
- Isolation Voltage ( $3.75\text{kV}_{\text{RMS}}, 5.3\text{kV}_{\text{PK}}$ )
- All electrical parameters 100% tested
- Drop in replacement for Toshiba TLP126

#### APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



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**ABSOLUTEMAXIMUMRATINGS**  
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 150°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

**INPUTDIODE**

Forward Current	±50mA
Power Dissipation	70mW

**OUTPUTTRANSISTOR**

Collector-emitter Voltage BV <sub>CEO</sub>	35V
Emitter-collector Voltage BV <sub>ECO</sub>	6V
Collector Current	50mA
Power Dissipation	150mW

**POWERDISSIPATION**

Total Power Dissipation	170mW
(derate linearly 2.26mW/°C above 25°C)	

**ELECTRICAL CHARACTERISTICS ( T<sub>A</sub> = 25°C Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V <sub>F</sub> )		1.2	1.4	V	I <sub>F</sub> =±20mA
Output	Collector-emitter Breakdown (BV <sub>CEO</sub> )	35			V	I <sub>C</sub> =0.1mA
	Emitter-collector Breakdown (BV <sub>ECO</sub> )	6			V	I <sub>E</sub> =10μA
	Collector-emitter Dark Current (I <sub>CEO</sub> )			100	nA	V <sub>CE</sub> =20V
Coupled	Current Transfer Ratio (CTR)	20		400	%	±1mA I <sub>F</sub> , 5VV <sub>CE</sub>
	Collector-emitter Saturation Voltage V <sub>CE(SAT)</sub>			0.2	V	±20mA I <sub>F</sub> , 1mA I <sub>C</sub>
	Input to Output Isolation Voltage V <sub>ISO</sub>	3750 5300			V <sub>RMS</sub> V <sub>PK</sub>	See note 1 See note 1
	Input-output Isolation Resistance R <sub>ISO</sub>	5x10 <sup>10</sup>			Ω	V <sub>IO</sub> = 500V (note 1)
	Output Rise Time tr Output Fall Time tf		4 3	18 18	μs μs	V <sub>CE</sub> =2V, I <sub>C</sub> =2mA, R <sub>L</sub> =100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.

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